

Application Manual

Programmable Crystal Oscillator SG-8506CA

SEIKO EPSON CORPORATION

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1. Overview

Programmable crystal oscillator: SG-8506CA is a low jitter programmable XO at any frequency. Its output frequency is programmable from 50 MHz to 800 MHz with almost 2 ppb resolution.

SG-8506CA consists of XO, PLL and LVPECL output buffer.

XO supplies stable reference clock to PLL with fundamental tone crystal.

PLL consists of a low jitter fractional-N PLL technology. The components for loop filter are embedded into IC, so no external filter component is needed.

- Programmable clock output frequency from 50 MHz to 800 MHz
- Frequency setting resolution is around 2 ppb
- Low jitter and high reliability clock source from the fundamental tone internal crystal
- Low jitter and low noise PLL
- One factory preset power-up default frequency
- Programmable one preset power-up default frequency (Only the blank Sample can be programmed one time with SG-Writer II)
- Factory preset device options
 - OE polarity
 - Output standby type: Hi-Z or OUT = "L", OUTN = "H"
 - I²C interface slave address
- Embedded resistors and capacitors for oscillator and loop filter for PLL
- I²C interface
- LVPECL output
- 8-pin ceramic 5 x 7 mm package
- 2.5 V or 3.3 V supply voltage modes
- -40 ℃ ~ +85 ℃ ambient operating temperature
- Pb-free / RoHS-compliant

[Evaluation Kit]

The evaluation kit of SG-8506CA is available. Please ask us for more information.

37050EAN	I2C Slave Addr	ess (Hex)	37	Search Addr	_	Register	Read Tabl	e			
STOSOLAN				Search Addi		Addr	Value	*			
G7050ECN	Reference Fre	quency 114	4.144444	[MHz]	+	00	00	-		×0	
3-8506CA						01	00			GND 2 GND2	
						02	00				8.1.5
ency Setting						03	00				
						04	00			PVSS	R4 PR3
luency Setting	vo. 0					05	00			Top .	
Output Free		156.050	000 [141			06	00				R50
Output Fre	quency	156.250	UUU [IVIH	4]		07	00	_		3	
Register	Register	Register				08	00	_		GND	
Address	Name	Value [Hex]	Divi	der		09	00				• • • • • • • • • • • • • • • • • • •
						OA	00	- 1		PVSS GND YC	
0x10	ODIV	09	20	•		08	00	- 1			
0x11	NINT	18		27		00	00	-		VC YC	
			-			00	00	*		Leenesse	PUP PUP
0x12,0x13,0x14	NFRAC	60A9DC	0.37	759185			Read			• • • • • • • • • • • • • • • • • • •	
0		_		Write and	Port						C40
		v	Vrite	Verify	F	SEL	OF		and the second second	esetetet	Collection 100 200 200 200 200 200 200 200 200 200
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						O 11b				a lessonerer	
											0
										EDRON SC	SEORCA EVA BOAR

2. Part Number

• Standard (Factory preset start-up frequency product)



• Blank (one-time programmable start-up frequency product)



3. Block Diagram



* If OE pin is configured as active low, OE pin is pulled down to GND with internal pull down resistor.

Figure 3.1. SG-8506CA Block Diagram

4. Pin Assignments

4.1. Pin Assignments



4.2. Pin Descriptions

Table 4.1Pin Descriptions

No.	Pin Name	Туре		Function					
1	NC	-	-	No Connect					
				Connect to GND/V _{CC} or open					
2	OE	Input	Pull-up/	Output Enable (Active High)					
			Pull-down	OE InputOUT, OUTN pin status"H" or OpenOutputs are enabled."L"High-impedance state or OUT = "L", OUTN = "H"Output Enable (Active Low)OE InputOUT, OUTN pin status H""H"High-impedance state or OUT = "L", OUTN = "H""Enable (Active Low)					
3	GND	Power	-	Negative Power Supply					
4	OUT	Output	-	Differential clock output. LVPECL interface levels.					
5	OUTN	Output	-						
6	V _{CC}	Power	-	Positive Power Supply					
7	SDA ^{*1}	Input/Output	-	I ² C Data Input/Output Input: LVCMOS interface levels, Output: Open drain					
8	SCL ^{*1}	Input	-	I ² C Clock Input					
Note: *Note	Note: "Pull-up" or "Pull-down" refers to SG-8506CA internal input resistors. *Note 1: External pull-up resistor to V_{CC} is necessary.								

5. Electrical Characteristics

5.1. Absolute Maximum Ratings

Item	Symbol	Condition	Min.	Тур.	Max.	Units	
Supply voltage, V _{CC}	V _{cc}	GND = 0 V	-0.3	-	4.0	V	
Pull-up voltage	V _{PU}	SDA, SCL	-0.3	-	4.0	V	
Input voltage 1	V _{in1}	GND = 0 V, Input pins except to SDA and SCL	GND - 0.3	-	V _{CC} + 0.3	V	
Input voltage 2	V _{in2}	GND = 0 V, SDA, SCL	GND - 0.3	-	4.0	V	
Storage temperature	Tstg	Store as bare product	-55	-	+125	C	
ESD sensitivity	ESD	НВМ	2000	-	-	V	
		MM	200	-	-		
Note: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those listed in the "DC characteristics" or "AC characteristics" is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.							

5.2. **DC Characteristics**

			GND	= 0 V, Ta	= -40 ~ +	-85 °C	
Item	Symbol	Conditions	Min.	Тур.	Max.	Units	
Positive supply voltage	V _{CC}	-	2.375	2.5/3.3	3.630	V	
Positive supply current ^{*1} Output enable mode	Icc	OE = Enable, Outputs terminated with 50 Ω to V_{CC} – 2.0 V	-	-	90	mA	
Positive supply current ^{*1} Output disable mode	I_ _{dis}	OE = Disable, Output standby type: Hi-Z	-	-	40	mA	
		OE = Disable, Output standby type: Fix (OUT = "L", OUTN = "H")	-	-	70	mA	
Operating temperature	Та	-	-40	-	+85	C	
Note 1: Guaranteed by design, characterization, and/or simulation only and not production tested.							

V _{CC} = 2.5 V - 5% ~ 3.3 V + 10%, GND = 0 V, Ta = -40 ~ +85 ℃							
Item	Symbol	Conditions	Min.	Тур.	Max.	Units	
Pull-up voltage	V _{PU}	SDA, SCL	V _{CC} x 0.7	-	3.630	V	
High level input voltage 1	V _{IH1}	OE	V _{CC} x 0.7	-	V _{CC} + 0.3	V	
High level input voltage 2	V _{IH2}	SDA, SCL, Pull Up Voltage = V_{PU}	V _{CC} x 0.7	-	3.630	V	
Low level input voltage	VIL	SDA, SCL, OE	-0.3	-	V _{CC} x 0.3	V	
High level input current 1	I _{IH1}	SDA, SCL, OE (Active High)	-	-	2	μA	
High level input current 2	I _{IH2}	OE (Active Low)	-	-	170	μA	
Low level input current 1	I_{IL1}	SDA, SCL	-2	-	-	μA	
Low level input current 2	I _{IL2}	OE (Active High)	-70	-	-	μA	
Low level output voltage	V _{OL}	SDA, at 3 mA sink current	0	-	0.4	V	
Low level output current	IOL	SDA, $V_{OL} = 0.4 V$	3	-	-	mA	
Pull-up resistor	R _{UP}	OE (Active High)	-	85	-	kΩ	
	R _{DOWN}	OE (Active Low)	-	35	-		
Input Capacitance ^{*1}	CIN	OE, SDA, SCL	-	5	-	рF	
Note 1: Guaranteed by design, characterization, and/or simulation only and not production tested.							

5.3. AC Characteristics

Table 5.3.	Output Frequency Characteristics
------------	---

	V _C	c = 2.5 V - 5%	~ 3.3 V + 10	0%, GND	= 0 V, Ta	= -40 ~ +	-85 °C
Item	Symbol	Condit	Min.	Тур.	Max.	Units	
Output frequency	fo	OUT, OUTN		50	-	800	MHz
Internal crystal frequency	f _{XTAL}	-	-	114.144	-	MHz	
Frequency reprogramming resolution	M _{RES}	-	2.2	-	2.8	ppb	
Frequency tolerance ^{*1}	f_tol	This parameter inc frequency tolerand supply voltage var years aging ² at 25	-50	-	+50	10 ⁻⁶	
Delta frequency for continuous output ^{*1}	-	From Center Frequeries defined by setting	uency that is NEW_FREQ bit	-500	-	+500	10 ⁻⁶
Setting time for large frequency change	t _{SET1}	From setting NEW output new freque	'_FREQ bit to ncy	-	-	1.5	ms
Setting time for small frequency change ^{*1}	t _{SET2}	< ±500 ppm from of frequency that is d setting NEW_FRE	-	-	100	μs	
SSB phase noise ^{*1}	F _{CN}	f _O <u>= 622.08 MHz</u> , f	rom carrier				
		$V_{CC} = 3.3 V^{*3}$	100 Hz	-	-76.5	-	dBc/Hz
			1 kHz	-	-103.1	-	
			10 kHz	-	-119.4	-	
			100 kHz	-	-121.3	-	
			1 MHz	-	-129.1	-	
			10 MHz	-	-146.8	-	
		$V_{CC} = 2.5 V^{4}$	100 Hz	-	-75.5	-	
			1 kHz	-	-101.1	-	
			10 kHz	-	-118.9	-	
			100 kHz	-	-121.3	-	
			1 MHz	-	-129.0	-	
			10 MHz	-	-146.7	-	
RMS phase jitter ^{*1, *4}	t _{PJ}	$f_{O} = 622.08 \text{ MHz}, \text{ I}$	ntegration range	: 12 kHz – 20) MHz (OC-4	8)	
		$V_{CC} = 3.3 V^{*3}$		-	0.3	-	ps
		$V_{CC} = 2.5 V^{*4}$		-	0.3	-	ps
		f _O = 622.08 MHz, I	ntegration range	e: 20 kHz – 50) MHz	1	1
		$V_{CC} = 3.3 V^{*3}$		-	0.3	-	ps
		$V_{CC} = 2.5 V^{*4}$		-	0.3	-	ps
		f _O = 622.08 MHz, I	ntegration range	e: 50 kHz – 80) MHz (OC-1	92)	1
		$V_{CC} = 3.3 V^{*3}$		-	0.3	-	ps
		$V_{CC} = 2.5 V^{*4}$		-	0.3	-	ps

Note 1: Guaranteed by design, characterization, and/or simulation only and not production tested.

Note 2: The aging in the frequency tolerance is from environmental tests results to the expectation of the amount of the frequency variation. This doesn't guarantee the product life cycle.

Note 3: $f_{XTAL} = 114.144$ MHz, Ta = +25 °C, V _{CC} = 3.3 V. Note 4: $f_{XTAL} = 114.144$ MHz, Ta = +25 °C, V _{CC} = 2.5 V.

Note 5: The output clock may contain spurious that depends on the settings of fo, f_{XTAL}, PLL and output divider. The RMS jitter may be worse, if the spurious is in integration range of RMS jitter. For more information, please contact us.



Frequency Change Time



Phase Noise Test Circuit

Table	5.4.	Serial	Interface

V_{CC} = 2.5 V - 5% ~ 3.3 V + 10%, GND = 0 V, Ta = -40 ~ +85 $^{\circ}$ C								
Item	Symbol	Conditions	Min.	Тур.	Max.	Units		
SCL clock frequency	f _{SCL}	-	-	-	400	kHz		
Hold time (repeated) START condition, After this period, the first clock pulse is generated.	t _{hd;sta}	-	0.6	-	-	μs		
Low period of the SCL clock	t _{LOW}	-	1.3	-	-	μs		
High period of the SCL clock	t _{HIGH}	-	0.6	-	-	μs		
Set up time for a repeated START condition	t _{su;sta}	-	0.6	-	-	μs		
Input data hold time	t _{HD;DAT}	-	0	-	-	μs		
Output data set-up time	t _{SU;DAT}	-	100	-	-	ns		
Rise time of both SDA and SCL signals ^{*1}	t _r	-	-	-	300	ns		
Fall time of both SDA and SCL signals	t _f	-	-	-	300	ns		
Set up time for STOP condition	t _{su;sto}	-	0.6	-	-	μs		
Bus free time between a STOP and START condition	t _{BUF}	-	1.3	-	-	μs		
Data valid time	$t_{VD:DAT}$	-	-	-	0.9	μs		
Data valid acknowledge time	t _{VD;ACK}	-	-	-	0.9	μs		
Note 1: Guaranteed by design, characterization, and/or simulation only and not production tested.								





Serial Interface

SG-8506CA

5.4. LVPECL

Table 5.5. LVPECL

	Vcc	$_{\rm C} = 2.5$ V - 5% ~ 3.3 V	+ 10%, GN	D = O V, Ta	a = -40 ~ +	85 °C				
Item	Symbol	Conditions	Conditions Min. Typ. Max							
Output load condition	L_PECL	Outputs terminated with 50 Ω	outputs terminated with 50 Ω to V_{CC} – 2.0 V -							
Rise time ^{*1}	t _R	-	-	-	400	ps				
Fall time ^{*1}	t _F	-	-	-	400	ps				
Symmetry ^{*1} (duty cycle)	SYM	-	45	50	55	%				
High level output voltage	V _{OH}	-	V _{CC} - 1.025	V _{CC} – 0.95	-	V				
Low level output voltage	V _{OL}	-	-	V _{CC} – 1.7	V _{CC} – 1.62	V				
OE disable delay time ^{*1}	t _{PXZ}	-	-	-	100	ns				
OE enable delay time ^{*1}	t _{pZX}	-	-	-	10	μs				
Note: OUT and OUTN are no	ot used as	single end								

OUT and OUTN are not used as single end. ote:

Note 1: Guaranteed by design, characterization, and/or simulation only and not production tested.



Output Rise/Fall Time, Symmetry (duty cycle)



Output AC Test Circuit









5.5. Startup

Table 5.6. Startup

		$V_{CC} = 2.5 V - 5\% \sim 3.3 V$	+ 10%, GN	D = O V, T a	a = -40 ~ +	·85 °C	
Item	Symbol	Conditions	Min.	Тур.	Max	Units	
V _{CC} ramp rate ^{*1}	R _{vcc}	V_{CC} from 0 V to $V_{CCMIN}.$	5 x 10 ⁻⁶	-	3	s	
Startup time ^{*2}	t_str	-	-	-	5	ms	
I ² C I/F enable time ^{*2}	t _{I2CEN}	-	-	-	5	ms	
Note 1: V _{CC} ramp must be monotonic.							

Note 2: Guaranteed by design, characterization, and/or simulation only and not production tested.



a) Output standby type: Hi-Z



Start-Up Time

6. Functions

6.1. Overview

The SG-8506CA has a XO, PLL and output buffer unit. The XO unit is composed of a fundamental mode crystal that generates stable reference clock for PLL. The output frequency is determined by the feedback divider and the output divider. The feedback divider can offer not only integer setting that achieves lower jitter, but also fractional setting that provides frequency in ppb resolution.

The device's default output frequency can be set at the factory and can be reprogrammed via l²C bus. Once the device is powered down, it will return to its factory-set default setting.

6.2. Setting of the Output Frequency

6.2.1. Calculation of the Frequency Setting

The output frequency (f_0) is determined by the VCO frequency (f_{VCO}) and the output divider (ODIV). This is shown:

$$f_0 = \frac{f_{VCO}}{ODIV} \tag{1}$$

The VCO frequency must be from 2.55 GHz to 3.20 GHz. Base on the relation between this limit and the formula (1), ODIV is calculated from the f_0 as shown in Table 6.1.

The VCO frequency is determined by the reference frequency (f_{REF}) from the XO and the feedback divider (N). The feedback divider (N) consists of both a 6-bit integer portion (N_{INT}) and a 24-bit fractional portion (N_{FRAC}) and provides the means for high-resolution frequency generation. The VCO frequency is calculated by:

$$f_{VCO} = f_{REF} \times N$$

= $f_{REF} \times \left(N_{INT} + \frac{N_{FRAC}}{2^{24}} \right)$ (2)

f _O [MHz]	ODIV	ODIV.ODIV register setting
50 ~ 57	56	0xF
53 ~ 67	48	0xE
64 ~ 80	40	0xD
80 ~ 100	32	0xC
91 ~ 114	28	0xB
106 ~ 133	24	0xA
128 ~ 160	20	0x9
159 ~ 200	16	0x8
182 ~ 229	14	0x7
213 ~ 267	12	0x6
255 ~ 320	10	0x5
319 ~ 400	8	0x4
364 ~ 457	7	0x3
425 ~ 533	6	0x2
510 ~ 640	5	0x1
638 ~ 800	4	0x0

Table 6.1. fo and ODIV

The output frequency (f_O) is shown:

$$f_{O} = \frac{f_{VCO}}{ODIV}$$
$$= f_{REF} \frac{\left(N_{INT} + \frac{N_{FRAC}}{2^{24}}\right)}{ODIV}$$

(3)

(4)

(5)

For example if the reference frequency (f_{REF}) is 114.144444 MHz and the output frequency is 120.0 MHz, ODIV is fixed to "24" from the Table 6.1. The setting of N, N_{INT}, N_{FRAC} is calculated:

$$N = N_{INT} + \frac{N_{FRAC}}{2^{24}} = \frac{f_{OUT} \times ODIV}{f_{REF}} = \frac{120.0 \times 10^6 \times 24}{114.1444444 \times 10^6} = 25.231188535690308$$

$$N_{INT} = floor(N) = floor(25.231188535690308) = 25$$

$$N_{FRAC} = (N - N_{int}) \times 2^{24} = (25.231188535690308 - 25) \times 2^{24}$$

= 0.231188535690308 \times 2^{24}
\approx 3878700 = 0x3B2F2C (6)

Depending on the fo, the ODIV may become two values.

For example if the fo is 380 MHz, ODIV can be 7 or 8. Even if either of the ODIV values is selected, the same fo can be gained by setting NINT and NFRAC but phase noise included in the output signal become different. Please evaluate the performances fully in your actual usage environment and select the ODIV.

 N_{FRAC} is a 24-bit value. By setting 6 bit of N_{INT} and 20 bit of N_{INT} frequency resolution is 10 ppb order. The lower 4 bit of the rest of the N_{FRAC} corresponds to the setting of the frequency in 1ppb order. By setting these values, the output frequency is changed very small, but the spurious of the output signal may change significantly. Please evaluate the performances fully in your actual usage environment and fix the lower 4 bit of the N_{FRAC} .

6.2.2. Reconfiguring Frequency Setting

The SG-8506CA has a "user register" and a "PLL register". The user register stores ODIV, NINT and NFRAC. It can be reprogrammed at any time when I²C bus is available. The PLL register is connected directly to the PLL. When the device is powered on, the default value programmed in the non-volatile memory is automatically fetched to the user register, and the PLL register is updated with it.

The PLL register is also updated with the user register, by writing PLL_CTRL.NEW_FREQ or PLL_CTRL.SML_CHG register. This flow is shown in Figure 6.1.



Figure 6.1. Reconfiguring Frequency Setting

First, ODIV, NINT, and NFRAC in the user register need to be changed. For details of the user register please refer to the chapter 6.

Next by writing 1 in the PLL_CTRL.NEW_FREQ register or PLL_CTRL.SML_CHG register, frequency setting can be forwarded from the user register to the PLL register. As a result, output signal of frequency (f_0) is updated. Difference between the PLL_NEW_FREQ register and the PLL_SML_CHG is shown in Table 6.2

Table 6.2. Up	dating the frequen	cy setting
---------------	--------------------	------------

No	Register	PLL calibration	Output signal	Frequency pull range
1	PLL_CTRL.NEW_FREQ	Y	Momentarily stopped and start over	50 MHz to 800 MHz
			after PLL is optimized	
2	PLL_CTRL.SML_CHG	Ν	Continuous output	Within the ±500 ppm window

As 1 is written in the PLL_CTRL.NEW_FREQ register, the output clock is momentarily stops and PLL is calibrated to new output frequency. After the calibration, output clock starts at any arbitrary point during a clock cycle. This method has no limitation in frequency change range and provides lower jitter. This also establishes a new center frequency. Circuitry receiving a clock from the SG-8506CA that is sensitive to glitches or runt pulses may have to be reset once this process is complete.

SG-8506CA

For output clock frequency changes less than ±500 ppm from the center frequency configuration, PLL_CTRL.SML_CHG register is available. By writing this register as 1, NINT and NFRAC in the user register are transferred to PLL register and the output frequency is updated without interruption to the output clock. Since the PLL is not calibrated, jitter might be increased. It is not guaranteed that the output frequency is in the frequency range defined by the old and new output frequency.



Figure 6.2. VCO frequency range

6.3. I²C interface

6.3.1. Connection of I²C Bus

The SG-8506CA can be used as a slave device of I^2C bus. The I^2C bus is composed of serial data line (SDA) and serial clock (SCL). The lines need to be both pulled up by external resistors. Electric level of the pull up resistor need to be above the Vcc so these are recommended to be pulled up to the Vcc. Also slave address of the slave devices on the I^2C bus must be unique.



The address of slave devices must be unique

Figure 6.3. Connection of I²C bus

6.3.2. I²C Bus Protocols Supported by the SG-8506CA

I2C bus protocols that can be supported by the SG-8506CA are shown in the below Table 6.3.

Feature	SG-8506CA
START condition	\checkmark
STOP condition	\checkmark
Acknowledge	\checkmark
Clock stretching	n/a
7-bit slave address	\checkmark
10-bit slave address	n/a
General Call address	n/a
Software Reset	n/a
Device ID	n/a

Table 6.3.	I ² C bus protocols supported by the SG-8506CA
------------	---

n/a = not applicable

6.3.3. START Condition and STOP Condition

Data communication on the I^2C bus starts by START condition (S). The START condition means that SDA changes from "H" to "L" when SCL is at "H". When the START condition occurs, I^2C bus becomes busy.

Data communication on the I^2C bus can be terminated by STOP condition (P). The STOP condition means that SDA changes from "L" to "H" when SCL is at "H". When the STOP condition occurs, I^2C bus becomes free.

When I^2C bus is busy, instead of STOP condition START condition can be generated, which is called repeated START condition (Sr). The I^2C bus maintains busy status. If the START or repeated START condition is received, I^2C interface circuit of the SG-8506CA is always reset, even if these START conditions are not positioned according to the proper format.



Figure 6.4. START and STOP condition

6.3.4. Byte Format and ACK/NACK

Data transmission and reception on I^2C is done in a unit of 8 bit = 1 byte. Each byte is followed by acknowledge bit. Data is transmitted by MSB first. Including acknowledge bit all SCL pulses are generated by Master.

The Acknowledge signal (ACK: A) is defined as follows: the transmitter (master transmitter or slave transmitter) releases the SDA line during the acknowledge clock pulse so the receiver can pull the SDA line "L" and it remains stable "L" during the "H" period of this clock pulse. When SDA remains "H" during this ninth clock pulse, this is defined as the Not Acknowledge signal (NACK: \overline{A}).

6.3.5. Read/Write to Register

Procedure of Read/Write to register is shown in the below Figure 6.5. The SG-8506CA can Read/Write single or multi byte data. The SG-8506CA slave address is able to be specified by the customer. It will be programmed to non-volatile memory at our factory.



Figure 6.5. Read/Write from/to register by I²C bus

7. Registers

7.1. List of registers

A daha a a	Register	Bit							
Address	name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
0x00	P_CODE0				0x46 (Ascii 'F	', Read Only)		
0x01	P_CODE1				0x06 (Re	ead Only)			
0x02	REV				0x01 (Re	ead Only)			
0x03	ID_CODE0				0x01 (Re	ead Only)			
0x04	ID_CODE1	-			I	D (Read Only	/)		
0x10	ODIV	-	-	-	-	ODIV			
0x11	NINT	-	-			NI	NT		
0x12	NFRAC_H		NFRAC_H						
0x13	NFRAC_M		NFRAC_M						
0x14	NFRAC_L		NFRAC_L						
0x15	PLL_CTRL0	OE_REG	-	-	-	-	NEW_FRE Q	SML_CHG	NVM_RES TORE
0x50	PLL_CTRL1	OE_REG	-	-	-	-	NEW_FRE Q	SML_CHG	NVM_RES TORE

Note: Please do not write values in the addresses that are not mentioned in this list. Please write 0 in the bit that is not defined.

7.2. Product Code 0 Register

Addroop	Register				В	Bit			
Address	name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
0x00	P_CODE0		P_CODE						
	Туре		R/O						
Default		0	1	0	0	0	1	1	0

Bit	Name	Function
7:0	P_CODE	Product code (0x46) Ascii Code 'F'

7.3. Product Code 1 Register

Addroop	Register				B	Bit			
Address	name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
0x01	P_CODE1		P_CODE						
-	Туре	R/O							
D	efault	0	0	0	0	0	1	1	0

Bit	Name	Function
7:0	P_CODE	Product code (0x41) 0x06

7.4. Revision Code Register

Addroop	Register		Bit						
Address	name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
0x02	REV		REV						
Туре					R	/0			
Default		0	0	0	0	0	0	0	1

Bit	Name	Function
7:0	REV	Revision code 0x01

7.5. ID Code 0 Register

Addroop	Register		Bit						
Address	name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
0x03	ID_CODE0		ID						
Туре					R	/0			
Default		0	0	0	0	0	0	0	1

Bit	Name	Function
7:0	ID	ID code 0x01

7.6. ID Code 1 Register

Addroop	Register		Bit							
Address	name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0	
0x04	ID_CODE1	-	ID							
Туре		-				R/O				
Default -		Depend on the product								

Bit	Name	Function
7	Reserved	Always read as 0.
6:0	ID	ID code

7.7. ODIV Register

Addroop	Register		Bit							
Address	name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0	
0x10	ODIV	-	-	-	-	ODIV				
Туре		-	-	-	-		R/	W		
Default		-	-	-	-		N١	/M		

Bit	Name		Function					
7:4	Reserved	Please write 0 at	Please write 0 at all the times.					
3:0	ODIV	Division ratio of	Division ratio of output divider					
		0x0. 4 0x1: 5	0x0: 4 0x4: 8 0x8: 16 0xC: 32 0x1: 5 0x5: 10 0x9: 20 0xD: 40					
		0x2: 6	0x6: 12	0xA: 24	0xE: 48			
		0x3: 7	0x7: 14	0xB: 28	0xF: 56			

7.8. NINT Register

م ما ما <u>بر</u> م م	Register		Bit							
Address	name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0	
0x11	NINT	-	-	NINT						
Type -			-			R/	W			
C	Default	-	-	NVM						

Bit	Name	Function					
7:6	Reserved	Please write 0 at all th	Please write 0 at all the times.				
5:0	NINT	Integer portion of the	nteger portion of the feedback divider (N _{INT})				
		Set	tting	Description			
		0x00 ~ 0x11,	0d ~ 17d	This setting shall not be configured			
		0x12	18d	N _{INT} = 18			
		0x20	32d	N _{INT} = 32			
		0x21 ~ 0x3F	33d ~ 63d	This setting shall not be configured			

7.9. NFRAC Register

Addrooo	Register				В	lit				
Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0	
0x12	NFRAC_H		NFRAC[23:16]							
0x13	NFRAC_M		NFRAC[15:8]							
0x14	NFRAC_L		NFRAC[7:0]							
	Туре		R/W							
C	Default	Bit7 Bit6 Bit5 Bit4 Bit3 Bit2 Bit1 Bit0 NFRAC[23:16] NFRAC[15:8] NFRAC[7:0] R/W NVM								

Bit	Name	Function
7:0	NFRAC[23:16] NFRAC[15:8] NFRAC[7:0]	Fractional portion of the feedback divider (N _{FRAC}) E.g. Setting in case N _{FRAC} is $0x123456$ NFRAC_H = $0x12$ NFRAC_M = $0x34$ NFRAC_L = $0x56$

7.10. PLL Control Register

Address	Register	Bit								
Address	Name	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0	
0x15 0x50	PLL_CTRL0 PLL_CTRL1	OE_REG	-	-	-	-	NEW_FR EQ	SML_CH G	NVM_RE STORE	
Туре		R/W	-	-	-	-	R/W	R/W	R/W	
Default		0	-	-	-	-	0	0	0	

PLL_CTRL0 and PLL_CTRL1 is an address shared register.

Bit	Name	Function					
7	OE_REG	Output enable register function LVPECL output buffer is enable when OE pin or this register is set as 1/High as shown below table.					
		LVPECL output buffer					
		OE pin (Active High) status OE pin (Active Low) status					
				H or Open	L	H	L or Open
		OE_REG	1	Enable	Enable	Enable	Enable
		value	0	Enable	Disable	Disable	Enable
6:3	Reserved	Please write 0 at all the times.					
2	NEW_FREQ	New frequency applied By writing 1, frequency setting configured in user register is forwarded to PLL register and output frequency is updated accordingly. This bit is automatically cleared once change of the output frequency and PLL calibration is completed. Note: Please refer to the item 6.2.2 for details of frequency change by this bit.					
1	SML_CHG	 New frequency applied (small change in frequency) By writing 1, frequency setting configured in user register is forwarded to PLL register and output frequency is updated accordingly. This bit is automatically cleared once change of the output frequency is done. Note: Please refer to the item 6.2.2 for details of frequency change by this bit. 					
0	NVM_RESTORE	Restore user register from NVM By writing 1, default value of user register is restored from non-volatile memory (NVM). This bit is automatically cleared once the register restore is done. Note: PLL register is not updated only by writing to this bit. In order to initialize the user register and the PLL register (= output frequency) at the same time, please write 0x05 to PLL_CTRL register (NEW_FREQ bit and NVM_RESTORE bit is written as 1).					



8. Dimensions



9. Device Marking

• Standard (Factory preset start-up frequency product)



• Blank Sample (SG-Writer II programmable start-up frequency product)



The above marking layout shows only marking contents and their approximate position, not actual font, size and exact position.

10. Soldering Pattern

Example of patterning design indicated as follows. In an actual design, please consider mounting density, the reliability of soldering, etc. and check whether performance is optimal.



11. Application Note

- 1. This device contains a crystal resonator, so please do not expose to excessive shock or vibration. The internal crystal resonator might be damaged in case that too much shock or vibration is produced mechanically. Be sure to check your machine condition in advance.
- 2. This device is made with C-MOS IC. Please take necessary precautions to prevent damage due to electrostatic discharge.
- 3. We recommend to use and store under room temperature and normal humidity to secure frequency accuracy and prevent moisture.
- 4. We will announce the discontinuance and switch to our successor before six months or more.
- 5. Recommendation reflow times are less than 3 times.

When there was a soldering error, please do alteration with a soldering iron. In this case, the iron ahead is equal to or less than +350 °C and asks within 5 s.

In case that this device is reflow soldered on the back side of your circuit board, please carefully verify the device is properly secured to prevent coming detached from card.

Soldering method	Good or No good
Reflow soldering (top side)	Good
Reflow soldering (back side)	Please carefully verify the device is properly secured to prevent coming detached from card.
Solder pot (static solder pot/flow solder pot)	No good
Iron soldering	Good

Soldering method

- 6. Ultrasonic cleaning can be used on this product, however, since the oscillator might be damaged under some conditions, please exercise caution in advance.
- 7. Protection against periodically mechanical vibration

While there is any given shock or mechanical vibration periodically to crystal products, such as, a cooling fan, a piezo sounder, a piezo buzzer, and a speaker to crystal products, output frequency and amplitude can be changed. Especially the quality of telecommunication equipment could be affected by this phenomenon. Although Epson's crystal products are designed to minimize the effect of mechanical vibration, we recommend checking them in advance.

8. The metal part of the surface (metal cap) is connected to GND #3 pin. Please take necessary precautions to prevent short circuit to GND by contact with the metal cap.

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- 9. Side leads as shown below are connected to IC internally. Therefore be careful for short or a fall of insulation resistance.



- 10. V_{CC} and GND pattern shall be as large as possible so that high frequency impedance shall be small.
- 11. Seiko Epson doesn't recommend to power on from intermediate electric voltage or extreme fast power on. Those powering conditions may cause no oscillation or abnormal oscillation.
- 12. Please design the output lines by characteristic impedance 50Ω and try to make the output lines as short as possible. A long output line may cause irregular output. Other high level signal lines may cause incorrect operation, so please do not place high-level signal line close to this device.
- 13. If OE (Active High), SDA or SCL pin is not used, please connect them to V_{CC}. In order to suppress surge, resister may be used for OE pin.
- 14. If output pin is connected to the ground when supply voltage is applied to product, the internal elements can be destroyed. So please use the products that always have connection with load resistance.
- 15. As with any high speed analog circuitry, the power supply pins for SG-8506CA are vulnerable to noise. In order to achieve optimum jitter performance, the 0.1 μF and 10 μF capacitor as shown below is required. These capacitors should be placed as close to Vcc (#3 pin) as possible. It is also recommended that the capacitors are placed on the device side of the PCB. To achieve best performance, it is recommended to place the filter composing devices. Please see next page.



SG-8506CA

■ Example of SG-8506CA schematic layout

This figure shows an example of this product's application schematic.

As with any high speed analog circuitry, the power supply pins for SG-8506CA are vulnerable to noise. In order to achieve optimum jitter performance, power isolation with filter device is required for power supply pins.

In order to achieve best performance of the power isolation filter, it is recommended that the filter composing devices is placed on the device side of the PCB as close to the power pins as possible. The component value of this filter is just an example; it may have to be adjusted.







Please place them on the device side of the PCB as close to the power pins as possible

Application Manual

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